

www.vishay.com

Vishay Semiconductors

Thyristor Surface Mount Phase Control SCR, 16 A



PRIMARY CHARACTERISTICS							
I _{T(AV)}	10 A						
V _{DRM} /V _{RRM}	1600 V						
V_{TM}	1.4 V						
I _{GT}	60 mA						
T_J	-40 °C to +125 °C						
Package	D ² PAK (TO-263AB)						
Circuit configuration	Single SCR						

FEATURES

- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Designed and qualified according JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912

ROHS COMPLIANT HALOGEN FREE

APPLICATIONS

- Input rectification (soft start)
- Vishay input diodes, switches and output rectifiers which are in identical package outlines

DESCRIPTION

The VS-16TTS16S-M3 high voltage series of silicon controlled rectifiers are specifically designed for medium power switching and phase control applications. The glass passivation technology used has reliable operation up to 125 °C junction temperature.

OUTPUT CURRENT IN TYPICAL APPLICATIONS								
APPLICATIONS SINGLE-PHASE BRIDGE THREE-PHASE BRIDGE UNITS								
NEMA FR-4 or G-10 glass fabric-based epoxy with 4 oz. (140 μm) copper	2.5	3.5						
Aluminum IMS, R _{thCA} = 15 °C/W	6.3	9.5	A					
Aluminum IMS with heatsink, R _{thCA} = 5 °C/W	14.0	18.5						

Note

• $T_A = 55 \, ^{\circ}\text{C}$, $T_J = 125 \, ^{\circ}\text{C}$, footprint 300 mm²

MAJOR RATINGS AND CHARACTERISTICS								
PARAMETER	TEST CONDITIONS	VALUES	UNITS					
I _{T(AV)}	Sinusoidal waveform	10	^					
I _{RMS}		16	A A					
V _{RRM} /V _{DRM}		1600	V					
I _{TSM}		200	A					
V _T	10 A, T _J = 25 °C	1.4	V					
dV/dt		500	V/µs					
dl/dt		150	A/μs					
TJ		-40 to +125	°C					

VOLTAGE RATINGS									
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{DRM} , MAXIMUM PEAK DIRECT VOLTAGE V	I _{RRM} /I _{DRM} AT 125 °C mA						
VS-16TTS16S-M3	1600	1600	10						



ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL		TEST CONDITIONS	VAL	UNITS				
PARAMETER	STIMBUL	STMBOL TEST CONDITIONS		TYP.	MAX.	UNITS			
Maximum average on-state current	I _{T(AV)}	T _C = 93 °C, 18	0° conduction, half sine wave	10					
Maximum RMS on-state current	I _{RMS}			1	6	А			
Maximum peak, one-cycle,	1	10 ms sine pul	lse, rated V _{RRM} applied	17	70	A			
non-repetitive surge current	I _{TSM}	10 ms sine pul	lse, no voltage reapplied	20	00				
Maximum 12t for funing	l ² t	10 ms sine pul	lse, rated V _{RRM} applied	14	14	A2a			
Maximum I ² t for fusing	1-1	10 ms sine pul	200		A ² s				
Maximum l ² √t for fusing	I ² √t	t = 0.1 ms to 1	t = 0.1 ms to 10 ms, no voltage reapplied						
Maximum on-state voltage drop	V _{TM}	10 A, T _J = 25 °	°C	1.4		V			
On-state slope resistance	r _t	T 105 °C		24.0		mΩ			
Threshold voltage	V _{T(TO)}	$T_{\rm J} = 125 ^{\circ}{\rm C}$	I _J = 125 ⁻ C		1.1				
Maximum reverse and direct leakage current	1/1	T _J = 25 °C	$V_R = \text{rated } V_{RRM} / V_{DRM}$	0.5					
Maximum reverse and direct leakage current	I_{RM}/I_{DM}	T _J = 125 °C	10						
Holding current	l _H	Anode supply T _J = 25 °C	Anode supply = 6 V, resistive load, initial $I_T = 1 \text{ A}$, $T_J = 25 \text{ °C}$			mA			
Maximum latching current	ΙL	Anode supply	200						
Maximum rate of rise of off-state voltage	dV/dt	$T_J = T_J \text{ max. lin}$	n 500		V/µs				
Maximum rate of rise of turned-on current	dI/dt		-	15	A/µs				

TRIGGERING									
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS					
Maximum peak gate power	P_{GM}		8.0	W					
Maximum average gate power	P _{G(AV)}		2.0	VV					
Maximum peak positive gate current	+ I _{GM}		1.5	Α					
Maximum peak negative gate voltage	- V _{GM}		10	V					
		Anode supply = 6 V, resistive load, T_J = - 10 °C	90						
Maximum required DC gate current to trigger	I _{GT}	Anode supply = 6 V, resistive load, T _J = 25 °C	60	mA					
		Anode supply = 6 V, resistive load, T _J = 125 °C	35						
		Anode supply = 6 V, resistive load, T _J = - 10 °C	3.0						
Maximum required DC gate voltage to trigger	V_{GT}	Anode supply = 6 V, resistive load, T _J = 25 °C	2.0	V					
Voltage to trigger		Anode supply = 6 V, resistive load, T _J = 125 °C	1.0	V					
Maximum DC gate voltage not to trigger	V_{GD}	T = 125 °C V = reted value	0.25						
Maximum DC gate current not to trigger	I_{GD}	T _J = 125 °C, V _{DRM} = rated value	2.0	mA					

SWITCHING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Typical turn-on time	t _{gt}	T _J = 25 °C	0.9	
Typical reverse recovery time	t _{rr}	T _{.1} = 125 °C	4	μs
Typical turn-off time	tq	1J = 125 C	110	

THERMAL - MECHANICAL SPECIFICATIONS									
PARAMETER	VALUES	UNITS							
Maximum junction and storage temperature range	T _J , T _{Stg}		-40 to +125	°C					
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	1.3	°C/W					
Typical thermal resistance, junction to ambient R _{thJA}		PCB mount ⁽¹⁾	40	C/VV					
Approximate weight			2	g					
Approximate weight			0.07	oz.					
Marking device	16TTS	16S							

Note

⁽¹⁾ When mounted on 1" square (650 mm²) PCB of FR-4 or G-10 material 4 oz. (140 μm) copper 40 °C/W. For recommended footprint and soldering techniques refer to application note #AN-994

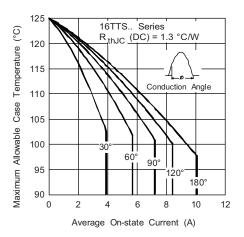


Fig. 1 - Current Rating Characteristics

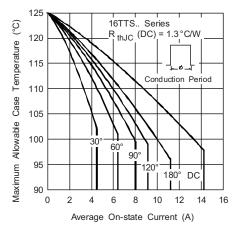


Fig. 2 - Current Rating Characteristics

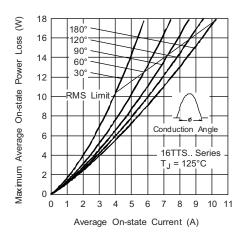


Fig. 3 - On-State Power Loss Characteristics

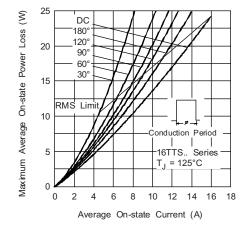


Fig. 4 - On-State Power Loss Characteristics

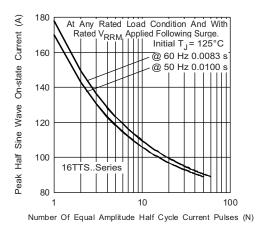


Fig. 5 - Maximum Non-Repetitive Surge Current

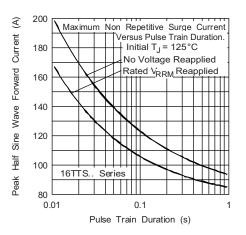


Fig. 6 - Maximum Non-Repetitive Surge Current

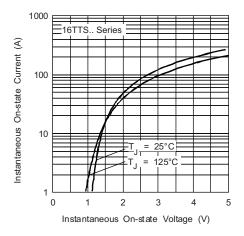


Fig. 7 - On-State Voltage Drop Characteristics

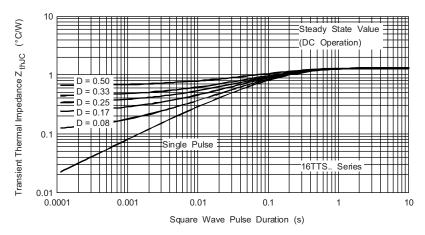


Fig. 8 - Thermal Impedance Z_{thJC} Characteristics

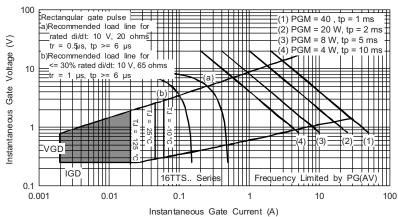
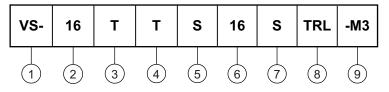


Fig. 9 - Gate Characteristics

ORDERING INFORMATION TABLE

Device code



- Vishay Semiconductors product
- 2 Current rating
- 3 Circuit configuration:

T = single thyristor

- 4 Package:
 - $T = D^2PAK (TO-263AB)$
- 5 Type of silicon:
 - S = standard recovery rectifier
- 6 Voltage rating: Voltage code x 100 = V_{RRM} (16 = 1600 V)
- 7 S = surface mountable
- 8 • None = tube
 - TRL = tape and reel (left oriented)
 - TRR = tape and reel (right oriented)
- 9 -M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)									
PREFERRED P/N BASE QUANTITY PACKAGING DESCRIPTIO									
VS-16TTS16S-M3	50	Antistatic plastic tubes							
VS-16TTS16STRL-M3	800	13" diameter plastic tape and reel							
VS-16TTS16STRR-M3	800	13" diameter plastic tape and reel							

LINKS TO RELATED DOCUMENTS						
Dimensions <u>www.vishay.com/doc?96164</u>						
Part marking information	www.vishay.com/doc?95444					
Packaging information	www.vishay.com/doc?96424					



D²PAK

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INC	HES	NOTES	NOTES	SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	STWBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			Е	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100	BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inches
- (7) Outline conforms to JEDEC® outline TO-263AB

Revision: 13-Jul-17 Document Number: 96164



Legal Disclaimer Notice

Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.